TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7W53FU, TC7W53FK

1. Functional Description

2-Channel Multiplexer/Demultiplexer

2. General

The TC7W53 is a high speed C²MOS Analog Multiplexer/

Demultiplexer fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation.

The TC7W53 has a 2 channel configuration.

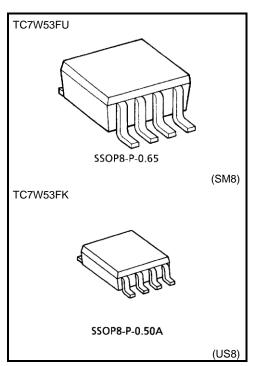
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal (V_{CC} – V_{EE}) can then be switched by the small logical amplitude (V_{CC} – GND) control signal.

For example, in the case of V_{CC} = 5 V, GND = 0 V, V_{EE} = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with a signal power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuit with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

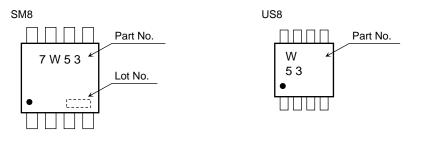
3. Features

- High speed: $t_{pd} = 15 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$, $V_{EE} = 0 \text{ V}$
- Low power dissipation: $ICC = 4 \mu A (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28 \% V_{CC}$ (min)
- Low ON resistance: $RON = 50 \Omega$ (typ.) at VCC-VEE = 9 V
- High degree of linearity: THD = 0.02 % (typ.) at V_{CC}-V_{EE} = 9 V
- Pin and function compatible with TC4W53



Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

4. Marking



Start of commercial production 1997-12

5. Absolute Maximum Ratings (Ta = 25°C) (Note)

Characteristics	Symbol	Rating	Unit	
	Vcc	–0.5 to 7	V	
Supply voltage range	$V_{CC} - V_{EE}$	-0.5 to 13	v	
Control input voltage	VIN	-0.5 to V _{CC} + 0.5	V	
Switch I/O voltage	VI/O	$V_{\mbox{\scriptsize EE}}$ –0.5 to $V_{\mbox{\scriptsize CC}}$ + 0.5	V	
Control input diode current	Іск	±20	mA	
I/O diode current	liok	±20	mA	
Switch through current	Ι _Τ	±25	mA	
DC V _{CC} /GND current	lcc	±25	mA	
Dower dissinction	De	300 (SM8)	mW	
Power dissipation	PD	200 (US8)	TIVV	
Storage temperature range	T _{stg}	-65 to 150	°C	
Lead temperature (10 s)	ΤL	260	°C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

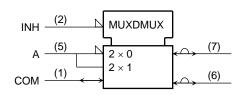
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

6. Truth Table

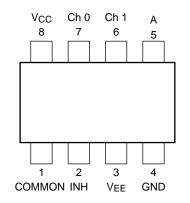
Contro	ol Input	On Channel
INH	А	On Channel
L	L	Ch 0
L	Н	Ch 1
Н	Х	None

X: Don't care

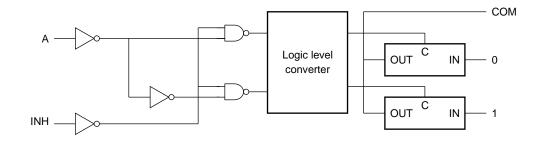
7. Logic Symbol



8. Pin Assignment (top view)



9. Logic Diagram



10. Operating Ranges

Characteristics	Symbol	Rating	Unit	
	V _{CC}	2 to 6		
Supply voltage	VEE	V _{EE} -6 to 0		
	$V_{CC} - V_{EE}$	2 to 12		
Control input voltage	VIN	0 to V _{CC}	V	
Switch I/O voltage	V _{I/O}	V _{EE} to V _{CC}	V	
Operating temperature range	T _{opr}	-40 to 85	°C	
		0 to 1000 (V _{CC} = 2.0 V)		
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns	
		0 to 400 ($V_{CC} = 6.0 \text{ V}$)		

11. Electrical Characteristics DC Electrical Characteristics

						-	Ta = 25°0	C		⊧ –40 5°C			
Characte	eristics	Symbol	Symbol Test Condition	V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit		
		Vінс		_	2.0	1.5			1.5				
	High level		—	_	4.5	3.15			3.15				
Control input					6.0	4.2			4.2				
voltage				_	2.0	_		0.5		0.5	V		
	Low level	VILC			4.5	_		1.35		1.35			
					6.0	_		1.8		1.8			
			VIN = VILC or VIHC	GND	4.5	_	85	180	_	225			
			$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5	_	55	120	_	150			
			$I_{I/O} \leq 2 \ mA$	-6.0	6.0	_	50	100		125	Ω		
ON resistance		Ron	Ron	GND	2.0	_	150						
			$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	GND	4.5	_	70	150	_	190			
			$V_{I/O} = V_{CC} \text{ or } V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	-4.5	4.5	_	50	100	_	125	-		
				-6.0	6.0	_	45	80	_	100			
Difference of C	N		VIN = VILC or VIHC	GND	4.5	_	10	30	—	35			
resistance betw		ΔRON	VI/O = VCC to VEE	-4.5	4.5	_	5	12	_	15	Ω		
switches			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0	_	5	10	_	12			
Input/output le	akage		$V_{OS} = V_{CC} \text{ or } GND$	GND	6.0	_	_	±60	_	±600			
current (switch o		IOFF	F $V_{IS} = GND \text{ to } V_{CC}$ $V_{IN} = V_{ILC} \text{ or } V_{IHC}$		-6.0	6.0			±100		±1000	nA	
Switch input le	Switch input leakage		Vos = Vcc or GND	GND	6.0	—	_	±60	—	±600	۳Å		
	current	ΙIZ	VIN = VILC or VIHC		117	-6.0	6.0	_		±100		±1000	nA
Control input c	urrent	lın	$V_{IN} = V_{CC} \text{ or } GND$	GND	6.0	_		±0.1		±1.0	μΑ		
Quieseent aur	nhu nurrant	las		GND	6.0	_	—	4	—	40	A		
Quiescent supply current ICC	Supply current ICC VIN = VCC OF GNL		ICC VIN = VCC or GND	-6.0	6.0	_		8	_	80	μA		

AC Electrical Characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 6 \text{ ns}$, GND = 0 V)

					Ta = 25°C			Ta = -40 to 85°C		
Characteristics	Symbol	Test Condition	VEE (V)	Vcc (V)	Min	Тур.	Max	Min	Max	Unit
		I/O —	GND	2.0	_	25	60	_	75	
Phase difference between	<u>ابار</u>		GND	4.5		6	12	_	15	ns
input and output	φι/Ο		GND	6.0		5	10		13	
			-4.5	4.5	_	4				
			GND	2.0		50	225	_	280	
Output anable time	tpZL	$R_L = 1 \ k\Omega$	GND	4.5		14	45	_	56	
Output enable time	t _{pZH}		GND	6.0		12	38	_	48	ns
			-4.5	4.5	—	14	—	_	—	
	tpLZ tpHZ	$ T_1 = K_2 $	GND	2.0		95	225		280	ns
Output disable time			GND	4.5		30	45		56	
Output disable time			GND	6.0	_	26	38	_	48	
			-4.5	4.5	—	26	_	—	—	
Control input capacitance	CIN			—		5	10		10	pF
Common terminal capacitance	CIS	—	-5.0	5.0	_	11	20	_	20	pF
Switch terminal capacitance	Cos		-5.0	5.0	_	7	15	_	15	pF
Feed through capacitance	CIOS		-5.0	5.0		0.75	2	—	2	pF
Power dissipation capacitance	CPD	(Note 1)	GND	5.0	_	67	_	_	_	pF

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: ICC (opr) = CPD • VCC • fIN + ICC/2



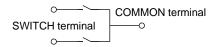
Analog Switch Characteristics (Note) (GND = 0 V, Ta = 25°C)

Characteristics	Symbol	Test Condition		Vcc	Тур.	Unit		
			V _{EE} (V)	(V)				
		V _{IN} = 4.0 Vp-p			-2.25	2.25	0.025	
Sine wave distortion (T.H.D)	—	RL = 10 kΩ, CL = 50 pF fin = 1 kHz	$V_{IN} = 8.0 Vp-p$		-4.5	4.5	0.02	%
· · ·			Vin =	11 Vр-р	-6.0	6.0	0.018	
			(Note1)		-2.25	2.5	120	
			.,	(Note2)	-2.20	2.0	95	
Frequency response	4			(Note1)	4.5	4.5	190	MHz
(switch ON)	tMAX			-4.5	4.5	150	IVITIZ	
						200		
				(Note2)	-6.0	6.0	190	
	_	VIN is centered at (V _{CC} -V _{EE})/2. Adju	st innut	for 0 dBm	-2.25	2.25	-50	
Feed Through attenuation (switch OFF)		$R_L = 600 \Omega$, $C_L = 50 pF$	stinput		-4.5	4.5	-50	dB
(,		fIN = 1 MHz, sine wave			-6.0	6.0	-50	
Crosstalk					-2.25	2.25	60	
(control input to signal	—	$R_L = 600 \Omega$, $C_L = 50 pF$ f _{IN} = 1 MHz, square wave (t _r = t _f = 6 ns)			-4.5 4.5 -6.0 6.0	140	mV	
output)						6.0	200	
		Adjust V _{IN} to obtain 0 dBm at input			-2.25	2.25	-50	
Crosstalk (between any switches)	(tches) — $R_L = 600 \Omega$, $C_L = 50 \text{ pF}$				-4.5	4.5	-50	dB
$f_{IN} = 1 \text{ MHz}$, sine wave		-6.0	6.0	-50				

Note: These characteristics are determined by design of device.

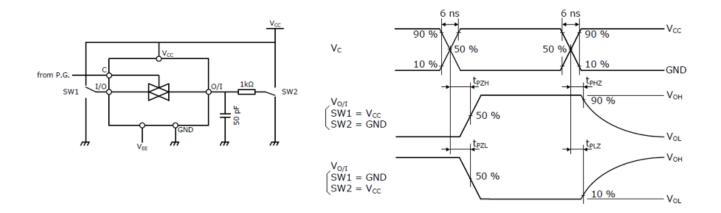
Note 1: Input COMMON terminal, and measure at SWITCH terminal.

Note 2: Input SWITCH terminal, and measure at COMMON terminal.

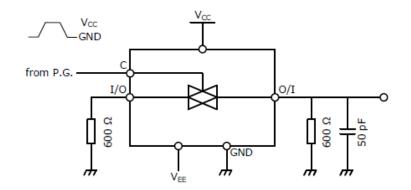


12. Switching Characteristics Test Circuits

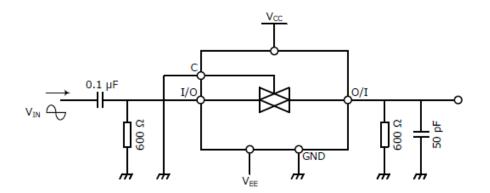
1. tpLZ, tpHZ, tpZL and tpZH



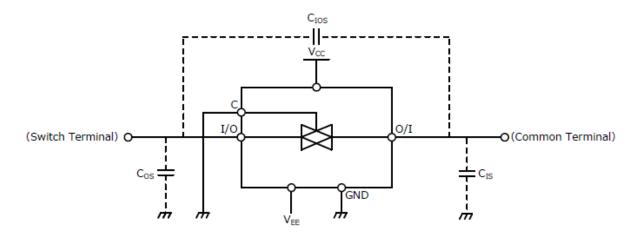
2. Cross Talk (control input-switch output) fIN = 1 MHz, duty = 50% and tr = tf = 6 ns



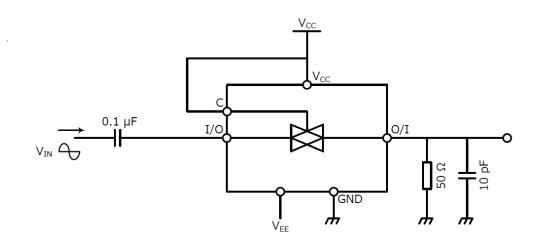
3. Feed Through Attenuation



4. Cios, Cis, Cos



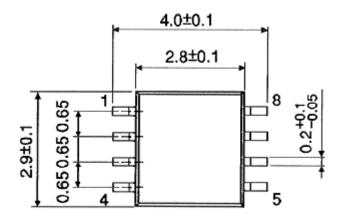
5. Frequency Response (switch ON)

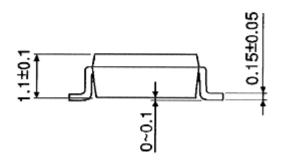


Package Dimensions

SSOP8-P-0.65

Unit : mm



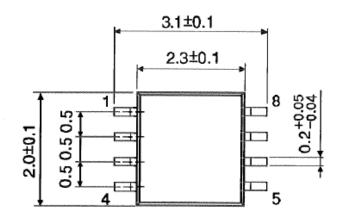


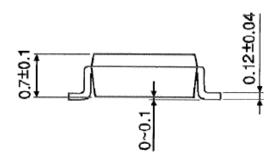
Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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